

# NOT RECOMMENDED FOR NEW DESIGN USE DMP2040USS



#### **DUAL P-CHANNEL ENHANCEMENT MODE MOSFET**

### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON) max</sub>	I <sub>D</sub> T <sub>A</sub> = +25°C
201/	40mΩ @ V <sub>GS</sub> = -4.5V	-5.8A
-20V	70m $Ω$ @ V <sub>GS</sub> = -2.5V	-4.4A

### **Description**

This new generation MOSFET is designed to minimize the on-state resistance  $(R_{DS(ON)})$  and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

### **Applications**

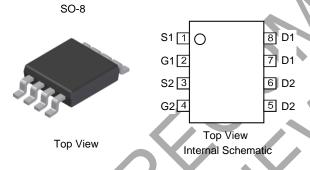
- Backlighting
- Power Management Functions
- DC-DC Converters

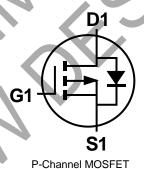
### **Features**

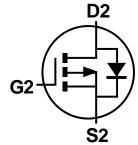
- Dual P-Channel MOSFET
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- · Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound.
   UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Lead
   Frame. Solderable per MIL-STD-202, Method 208 ©3
- Weight: 0.072 grams (Approximate)







P-Channel MOSFET

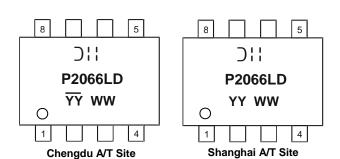
### Ordering Information (Note 4)

Part Number	Case	Packaging
DMP2066LSD-13	SO-8	2500/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



⊃¦¦ = Manufacturer's Marking
 P2066LD = Product Type Marking Code
 YYWW = Date Code Marking
 YY or YY = Year (ex: 18 = 2018)
 WW = Week (01 to 53)
 YY = Date Code Marking for SAT (Shanghai Assembly/ Test Site)

YY = Date Code Marking for SAT (Shanghai Assembly/ Test Site)
YY = Date Code Marking for CAT (Chengdu Assembly/ Test Site)



### NOT RECOMMENDED FOR NEW DESIGN **USE DMP2040USS**

DMP2066LSD

## **Maximum Ratings** $(@T_A = +25^{\circ}C, \text{ unless otherwise specified.})$

Chara	acteristic		Symbol	Value	Unit
Drain-Source Voltage			V <sub>DSS</sub>	-20	V
Gate-Source Voltage			V <sub>GSS</sub>	±12	V
Drain Current (Note 5)	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	-5.8 -4.6	А
Pulsed Drain Current (Note 6)			I <sub>DM</sub>	-20	Α

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P <sub>D</sub>	2.0	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{ heta JA}$	62.5	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

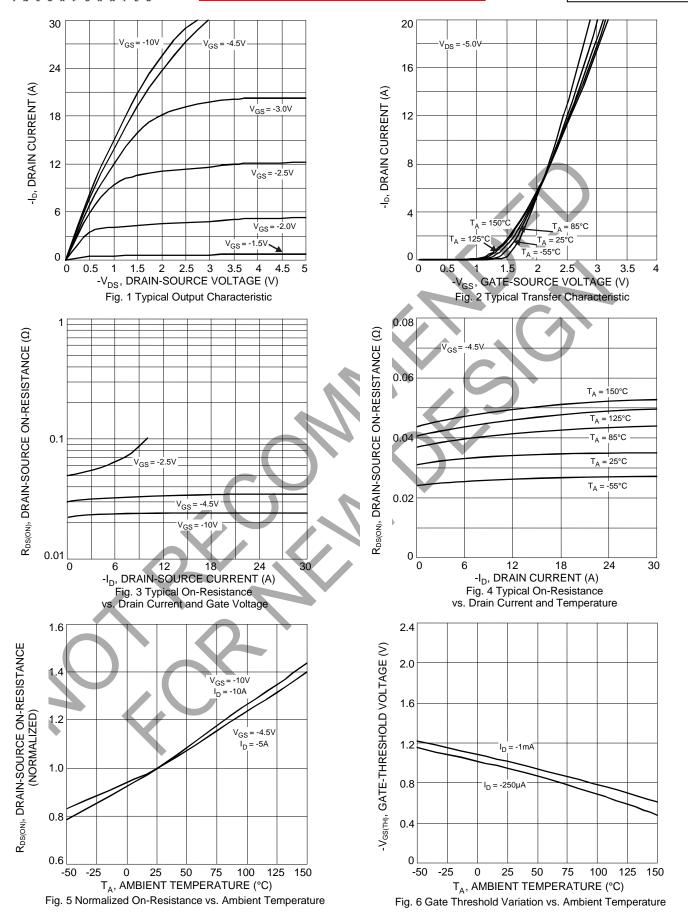
## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)					rest containon	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-20			V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	17.	_	-1	μA	V <sub>DS</sub> = -20V, V <sub>GS</sub> = 0V
Gate-Source Leakage	I <sub>GSS</sub>	177	_	±100	nA	$V_{GS} = \pm 12V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)		13				
Gate Threshold Voltage	V <sub>GS(TH)</sub>	-0.6	-0.94	-1.2	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
Static Drain-Source On-Resistance	R <sub>DS</sub> (ON)	\	29 55	40 70	mΩ	$V_{GS} = -4.5V, I_{D} = -4.6A$ $V_{GS} = -2.5V, I_{D} = -3.8A$
Forward Transconductance	<b>g</b> fs	1	9	_	S	$V_{DS} = -10V, I_{D} = -4.6A$
Diode Forward Voltage (Note 7)	V <sub>SD</sub>	-0.5	-0.72	-1.4	V	$V_{GS} = 0V, I_{S} = -2.1A$
DYNAMIC CHARACTERISTICS				•		
Input Capacitance	C <sub>iss</sub>		820	_	pF	
Output Capacitance	Coss		200	_	pF V <sub>DS</sub> = -15V, V <sub>GS</sub> =	$V_{DS} = -15V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>		160	_	pF	1 - 1.00012
Gate Resistance	R <sub>G</sub>	_	2.5	_	Ω	$V_{DS} = 0V, V_{GS} = 0V$ f = 1.0MHz
SWITCHING CHARACTERISTICS	· ·	•		•	•	
Total Gate Charge	Q <sub>G</sub>	_	10.1	_		$V_{DS} = -10V, V_{GS} = -4.5V,$ $I_{D} = -5.9A$
Gate-Source Charge	Q <sub>GS</sub>	_	1.5	_	nC	
Gate-Drain Charge	$Q_{GD}$	_	4.3	_		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	4.4	_		
Rise Time	t <sub>R</sub>	_	9.9	_		$V_{DS} = -10V$ , $V_{GS} = -4.5V$ , $I_{D} = -1A$ , $R_{G} = 6.0\Omega$
Turn-Off Delay Time	t <sub>D(OFF)</sub>	_	28.0	_	ns	
Fall Time	t <sub>F</sub>		23.4			

5. Device mounted on 2 oz. 1" x 1" Copper pads on 2" x 2" FR-4 PCB.

6. Pulse width ≤10µS, Duty Cycle ≤1%.
7. Short duration pulse test used to minimize self-heating effect.

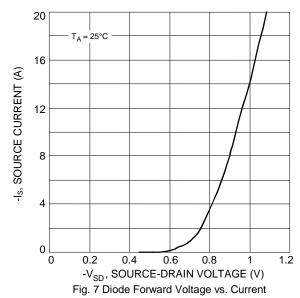


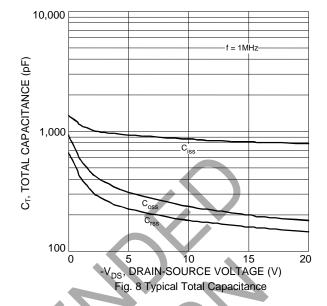




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### DMP2066LSD



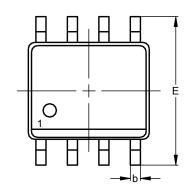


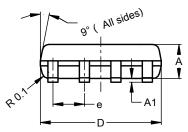


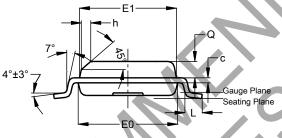
### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8





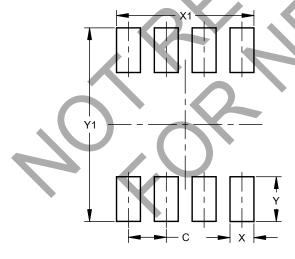


SO-8					
Dim	Min	Max	Тур		
Α	1.40	1.50	1.45		
A1	0.10	0.20	0.15		
b	0.30	0.50	0.40		
С	0.15	0.25	0.20		
D	4.85	4.95	4.90		
Е	5.90	6.10	6.00		
E1	3.80	3.90	3.85		
E0	3.85	3.95	3.90		
е			1.27		
h			0.35		
	0.62	0.82	0.72		
Q	0.60	0.70	0.65		
All Dimensions in mm					

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

**SO-8** 



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Υ	1.505
V1	6.50



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DMP2066LSD

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